Part-A

1. A TTL circuit with totem pole output has
a) High output impedance
b) Low output impedance
c.) Very high output impedance
d) Low speed operation
2. The digital logic family which has minimum power dissipation is
a. TTL
b. RTL
c. DTL
d. CMOS
3. The logic family which has highest noise margin is
a. TTL
b. ITL
c. MOS
d. CMOS
4. The fastest saturated logic family
a. TTL
b. ILL
c. MOS
d. ECL
5. The integrated circuit used in watches and calculators are of
a. Transistor Transistor Logic
b. Emitter Coupled Logic
c. Metal Oxide Semiconductor Logic
d. Complementary Metal Oxide Semiconductor Logic
6. In RTL NOR gate, the output is at logic 1 only when all the inputs are at
a) logic 0
b) logic 1
c) +10V
d) Floating
7. The role of the is to convert the collector current into a voltage in RTL.
a) Collector resistor
b) Base resistor

c) Capacitor			
d) Inductor			
8. Which of following is not advantage of RTL is a) It uses a maximum number of resistors			
c) High noise creation			
d) It uses minimum number of transistors			
9. The additional transistor and diode is used to increase DTL			
a. Size			
b. Fan-in			
c. Fan-out			
d. Speed			
10. The main advantage of TTL with Totem pole output as compared to other TTL types are -			
a. Higher fan-in and higher fan-out			
b. Fast switching and low power dissipation			
c. Higher noise margin			
d. Lower cost			
11. Speed of operation of digital ICs are specified in terms of			
A. Fan-in			
B. Fan-out			
C. Propogation delay			
D. Noise Margin			
ANSWER: C			
12. The expression for power dissipation of logic gates is given by			
A. $I_{cc(avg)} * V_{cc} * n$			
B. I _{ccH} * V _{cc} * n			
C. I _{ccL} * V _{cc} * n			
D. $I_{ccH} * V_{cc}$			
ANSWER: A			
13. Transistor acts a gate in digital IC.			
A. AND			
B. OR			
C. NOT			

D.	NAND	
AN	NSWER: C	
14. Mediu	m Scale Integration IC chips refers to	gates/chip
A.	10	
B.	100	
C.	530	
D.	1000	
AN	NSWER: B	
15. MOSF	FET is a	
a)	Current controlled device	
b)	Voltage controlled device	
c)	Uncontrolled device	
d)	Pressure controlled device	
An	ns: B)
16. MOSF	FETs are widely used in digital circuits due to	
a)	Less noise	
b)	Low power consumption	
c)	More power consumption	
d)	Less reliability	
An	ns: B	
17. MOSF	FET stands for	
a)	Metal oxide surface FET	
b)	Metal oxide selenium FET	
c)	Metal oxide silicon FET	
d)	Metal oxide semiconductor FET	
An	ns: D	
18. Transf	Fer characteristics of MOSFET is drawn between	
a)	Vds Vs Id, keeping Vgs constant	
b)	Vds Vs Ig, keeping Vgs constant	
c)	Vgs Vs Id, Keeping Vds constant	
d)	Vgs Vs Ig, Keeping Vds constant	
An	ns: C	
19. Which	of the following is not a terminal of MOSFET?	
a)	Drain	

	c)	Base		
	d)	Gate		
	Ar	as: C		
	20. Inverte	er, with identical transistors, has		
	a)	High tPHL		
	b)	High tPLH		
	c)	Equal tPHL and tPLH		
	d)	Low tPLH		
	Ar	as: C		
	21. NMOS	S device is turned 'ON' by applying		
	a)	Positive gate to source voltage		
	b)	Negative gate to source voltage		
	c)	Positive gate to drain voltage		
	d)	Negative gate to drain voltage		
	Ar	ns: A		
	22. CMOS	S logic circuit of inverter has		
	a)	One PMOS and One NMOS		
	b)	Two PMOS		
	c)	Two NMOS		
	d)	One PMOS		
	Ar	ns: A		
23. What is the equivalent to Binary 1 in the negative logic convention?				
	a)	Vdd		
	b)	0		
	c)	-Vdd		
	d)	2Vdd		
	Ar	as: B		
	24. What is	is the role of p-MOS transistor in CMOS logic circuit?		
	a)	Load		
	b)	Pull down network		
	c)	Pull up network		
	d)	Not used in CMOS circuits		
	Ar	ns: C		

b) Source

- 25. The time required for a gate or inverter to change its state is called
 - a. Rise time
 - b. Decay time
 - c. Propagation time
 - d. Charging time
- 26. The time required for a pulse to change from 10 to 90 percent of its maximum value is called
 - a. Rise time
 - b. Decay time
 - c. Propagation time
 - d. Operating Speed
- 27. The maximum frequency at which digital data can be applied to gate is called
 - a. Operating Speed
 - b. Propagation Speed
 - c. Binary level transaction period
 - d. Charging time
- 28. The time required for a pulse to decrease from 90 to 10 per cent of its maximum value is called
 - a. Rise time
 - b. Decay time
 - c. Binary level transaction period
 - d. Propagation Delay
- 29. Which of the following is also known as tri-state?
 - a. output port
 - b. input port
 - c. parallel port
 - d. output-input port
- 30. The third state of Tri-state buffer mainly known as?
 - a. High-resistance
 - b. Low-Impedance
 - c. Low-Resistance
 - d. High-Impedance
- 31. The primary purpose of a three-state buffer is usually
 - a. to provide isolation between the input device and the data bus

b. to provide the sink or source current required by any device connected to its output				
without loading down the output device				
c. temporary data storage				
d. to control data flow				
32. When is it important to use a three-state buffer?				
a. when two or more outputs are connected to the same input				
b. when all outputs are normally HIGH				
c. when all outputs are normally LOW				
d. when two or more outputs are connected to two or more inputs				
32.FPGA is used for				
a) Analog circuit design				
b) Digital logic circuit design				
c) AC circuit design				
d) DC circuit Design				
33.FPGA device are type.				
a) SROM				
b) EPROM				
c) SLD				
d) PLD				
34.FPGA stands for				
a) Field Program Gate Array				
b) First Program Gate Array				
c) Field Programmable Gate Array				
d) First programmable Gate Array				
35.In FPGA the Vertical and horizontal directions are separated by				
a) A channel				
b) A line				
c) A flip-flop				
d) A strobe				
36. Which of the following can be the name of an entity?				
a) NAND				
b) Nand_gate				
c) Nand gate				
d) AND				

37 The default mode for a port variable in Hardware descriptive language is
a) IN
b) OUT
c) INOUT
d) BUFFER
38. In HDL Which of the following is the basic building block of a design?
a) Architecture
b) Entity
c) Process
d) Package
39. A package in VHDL consists of
a) Commonly used architectures
b) Commonly used tools
c) Commonly used data types and subroutines
d) Commonly used syntax and variables
40. The major drawback in behavioral modeling is
a) Asynchronous delays
b) Simulation
c) No delay
d) Supports single driver only
41. In structural modeling which is the following statement is used?
a) portmap()
b) process()
c) if-else
d) case
42. Under which modelling the functionality of the logic system and basic blocks are
described?
a) Behavioral
b) Structural
c) Dataflow
d) Component
43. In Structural modelling the Ports are also known as to the component.
a) Structure
b) Behavior

- c) Function
- d) Interface
- 44. The depletion N-channel MOSFET
 - a. Can be operated as a JFET with zero gate voltage
 - b. Can be operated as an enhancement MOSFET by applying +ve bias to gate
 - c. Can be operated as an enhancement MOSFET by applying -ve bias to gate
 - d. Cannot be operated as an enhancement MOSFET

Ans: B

- 45. Which action plays a significant role in enhancing the conductivity of channel by inducing the free electrons especially in enhancement mode of N-channel MOSFET?
 - a) Filter action
 - b) Inductor action
 - c) Capacitor action
 - d) Resistor action

Ans: C

- 46. Why is the N-channel MOSFET considered better than the P-channel MOSFET?
 - A) Low noise levels
 - B) TTL compatibility
 - C) Lower input impedance
 - D) Faster operation

Ans: D

- 47. What is the value of typical threshold voltage CMOS inverter?
 - A) 0.001 to 0.002 Vdd
 - B) 0.001 to 0.02 Vdd
 - C) 0.01 to 0.02 Vd
 - D) 0.1 to 0.2 Vd

Ans: D

- 48 .When both nMOS and pMOS transistors of CMOS logic design are in OFF condition, the output is:
 - A) 1 or Vdd or HIGH state
 - B) 0 or ground or LOW state
 - C) High impedance or floating(Z)
 - D) Either 1 or 0

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